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纳米级Sr₂FeMoO₆/CeO₂复合材料磁致电阻效应研究

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Enhanced low field magnetoresistance in nanostructured Sr₂FeMoO₆/CeO₂ composites

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- 摘要
- 参考文献
- 相关文章

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背景资料

摘要 研究具有纳米级晶粒尺寸的(Sr₂FeMoO₆)_{1-x}(CeO₂)_x复合材料的电输运性质。发现其低场磁致电阻效应在整个温区内要高于纯Sr₂FeMoO₆/CeO₂多晶材料。外加磁场为2 kOe时, x=0.3的复合材料在10 K与300 K的磁致电阻分别为纯SFMO样品的1.7与1.3倍。表明载流子在晶界处的隧穿效应加强了其磁致电阻效应。

关键词: 溶胶 凝胶法 Sr₂FeMoO₆ 磁致电阻 溶胶 凝胶法 Sr₂FeMoO₆ 磁致电阻

Abstract: The electric transport properties of the nanostructured (Sr₂FeMoO₆)_{1-x}(CeO₂)_x composition were investigated. It was found that the low field magnetoresistance of the composition is higher than that of the pure Sr₂FeMoO₆/CeO₂ material in the whole region of temperature. The magnetoresistance ratios at 10 K and 300 K with H=2 kOe for the x =0.3 sample are 1.7 times and 1.3 times as large as that for the pure Sr₂FeMoO₆, respectively. This means that the spin dependent tunneling at the interfaces of grain boundaries is responsible for the enhanced MR.

Key words: Sr₂FeMoO₆ magnetoresistance Sol gel method Sr₂FeMoO₆ magnetoresistance

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